



Docket No. 201009-007000

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:) Art Unit: 2812
Stephen J. FONASH, *et al.*) Confirmation No.: 7746
Application No.: 09/836,449) Examiner: Richard A. Booth
Filed: April 17, 2001) Date: December 19, 2005
For: DEPOSITED THIN FILMS AND THEIR USE
IN SEPARATION AND SACRIFICIAL LAYER
APPLICATIONS

CROSS REFERENCE TO RELATED APPLICATION(S)

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Pursuant to Applicants duty of candor, Applicants wish to inform the Examiner of the following application(s) directed to related technical subject matter:

Serial No.: 10/317,153

Attorney Docket No.: 201009-001000

Filing Date: December 12, 2002

Title: Chemical Reactor Templates: Sacrificial Layer Fabrication and Template Use

Serial No.: 10/340,723

Attorney Docket No.: 201009-002000

Filing Date: January 13, 2003

Title: Use Of Sacrificial Layers In The Manufacture Of High Performance Systems On Tailored Substrates

Serial No.: 11/008,989

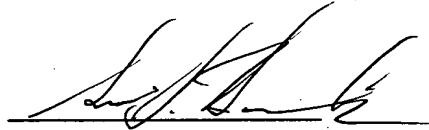
Attorney Docket No.: 201009-008000

Filing Date: December 13, 2004

Title: Controlled Nanowire Growth In Permanent Integrated Nano-Templates And Method Of Fabricating Sensor And Transducer Structures

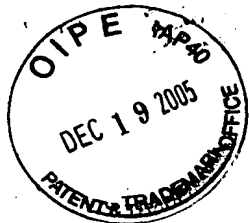
The above applications are commonly assigned and directed to related technical subject matter. The Commissioner is hereby authorized to charge the required fee of \$180.00 to comply with the provisions of 37 C.F.R. § 1.97(c), or credit any overpayment to Deposit Account No. 19-2380 (201009-007000).

Respectfully submitted,

A handwritten signature in black ink, appearing to read 'Scott J. Hawranek', is written over a horizontal line.

Scott J. Hawranek
Reg. No. 52,411

Nixon Peabody LLP
9th Street N.W.
Suite 900
Washington, D. C. 20004
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INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure as set forth in 37 C.F.R. § 1.56, the accompanying information is being submitted in accordance with 37 C.F.R. §§ 1.97 and 1.98.

Pursuant to 37 C.F.R. § 1.98, a copy of each of the documents cited is enclosed. However, copies of the listed U.S. patents and U.S. patent application publications are not enclosed since it is no longer required according to the July 11, 2003, waiver of the requirement for copies of cited U.S. patents and U.S. patent application publications in national patent applications filed after June 30, 2003 and international applications entering the national stage under 35 U.S.C. § 371 after June 30, 2003.

It is requested that the accompanying PTO-1449 be considered and made of record in the above-identified application. To assist the Examiner, the documents are listed on the attached form PTO-1449. It is respectfully requested that an Examiner initialed copy of this form be returned to the undersigned. Also, attached is a cross reference to related application(s) to be reviewed by the Examiner.

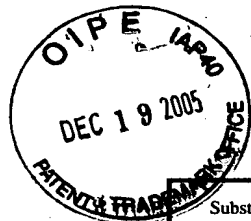
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Substitute for form 1449A/PTO

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(use as many sheets as necessary)

Sheet 1 of 4

Complete if Known

Application Number	09/836,449
Filing Date	April 17, 2001
First Named Inventor	Stephen J. FONASH
Art Unit	2812
Examiner Name	Richard A. BOOTH
Attorney Docket Number	201009-007000

U.S. PATENT DOCUMENTS

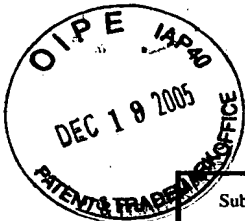
Examiner Initials*	Cite No. ¹	U.S. Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code ² (if known)			
		US-6,486,041	11/26/02	Henley, et al.	
		US-6,399,177	06/04/02	Fonash, et al.	
		US-6,372,608	04/16/02	Shimoda, et al.	
		US-6,225,192	05/01/01	Aspar, et al.	
		US-6,214,701	04/10/2000	Matsushita, et al.	
		US-6,158,824	12/12/00	Yonemura, et al.	
		US-5,854,123	12/29/98	Sato, et al.	
		US-5,641,709	06/24/97	Lee	
		US-5,690,753	11/25/97	Kawauchi, et al.	
		US-5,690,763	11/25/97	Ashmead, et al.	
		US-5,811,348	09/22/98	Matsushita, et al.	
		US-5,866,204	02/02/99	Robbie, et al.	
		US-6,555,443	04/29/03	Artmann, et al.	
		US-5,242,863	09/07/93	Xiang-Zheng, et al.	
		US-6,774,010	08/10/04	Chu, et al.	
		US-5,594,171	01/14/97	Ishida, et al.	
		US-5,811,348	09/22/98	Matsuchita, et al.	
		US-5,854,123	12/29/98	Sato, et al.	
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		US-6,372,608	04/16/02	Shimoda, et al.	
		US-6,486,041 B2	11/26/02	Henley, et al.	
		US-6,399,177	06/04/02	Fonash, et al.	
		US-6,449,079 B1	09/10/02	Hermann	
		US-6,555,443	04/29/03	Artman, et al.	
		US-6,774,010	08/10/04	Chu, et al.	
		US-5,854,123	12/29/98	Sato, et al.	
		US-6,905,655	06/14/05	Sato, et al.	
		US-2002/0068419	06/06/02	Sakaguchi, et al.	
		US-2002/0197836	12/26/02	Lyer, et al.	
		US-2002/0020053	2/21/2002	Fonash, et al.	

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Country Code ³ Number ⁴ Kind Code ⁵ (if known)				
		DE 198 41 430	05/25/00			
		EP 0 993 029	04/12/00			

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Complete if Known	
				Application Number	09/836,449
				Filing Date	April 17, 2001
				First Named Inventor	Stephen J. FONASH
				Art Unit	2812
				Examiner Name	Richard A. BOOTH
Sheet	2	of	4	Attorney Docket Number	201009-007000

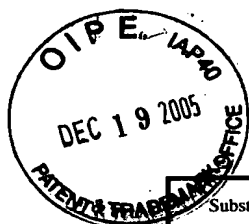
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		Country Code ³	Number ⁴ Kind Code ² (if known)			
		EP	895 276 A1	02/99		
		EP	0 297 258	04/08/92		
		WO	00/74932 A1	12-14-00		
		WO	01/80286 A2	10-25-01		√
		WO	03/050854 A2	06/19/03		
		WO	99/27325 A2	06/99		

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
		LEE, et al., A novel fabrication technology for Si TFTs on flexible substrates, ECS Extended Abstract No. 791, Electrochemical Society meeting, October 2000.	
		WAGNER, et al., Flexible display enabling technology, Cockpit Displays VIII: Displays for Defense Applications, Proc. SPIE Vol. 4362, p. 226-244, September, 2001.	
		STURM, et al., Enabling Technologies for Plastic Displays, Cockpit Displays IX: Displays for Defense Applications, Proc. SPIE Vol. 4712, p. 222-236, August 2002.	
		LI, et al., Transfer approach toward fabricating poly-Si TFTs on plastic substrates ECS Extended Abstracts No. 647, Electrochemical Society meeting, Oct., 2002.	
		LEE, et al., High Performance Poly-Si TFTs on Plastic Substrates Using a Nano-Structured Separation Layer Approach, IEEE Electron Device Letters, Vol. 24, No. 1, January 2003.	
		KALKAN, et al., Nanocrystalline Si Thin Films With Arrayed Void-Column Network Deposited By High Density Plasma, Journal Of Applied Physics, Vol. 88, No. 1, July 1, 2000, PP. 555-561.	
		TAYANAKA, et al., Thin-Film Crystalline Silicon Solar Cells Obtained By Separation Of A Porous Silicon Sacrificial Layer", Crystalline Silicon Solar Cells And Technologies, Vol. 2, July 6, 1998, PP. 1272-1277.	
		CHOU, et al., Nanoimprint lithography, J. Vac. Sci., Tech. B, 1996, 14(6), 4129-4133.	

Examiner Signature		Date Considered	
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(use as many sheets as necessary)

Sheet 3 of 4

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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

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		COLBURN, et al., Step and Flash Imprint Lithograph, Solid State Technology, July 2001.	
		RESNICK, et al., High Resolution Templates for Steps and Flash Imprint Lithograph, J. Microlith., Microfab., Microsyst., Vol. 1 No. 3, October 2002.	
		BENDER, et al., Multiple Imprinting in UV based Nanoimprint Lithography: Related Materials Issues, Microelectronic Engineering, 61-62 (2002), pp. 407-413.	
		TANIGUCHI, et al., Measurement of Adhesive Force Between Mold and Photocurable Resin in Imprint Technology, Jpn. J. Appl. Phy. Vol. 41, 2002, 4194-4197.	
		MARSEN, et al., Fullerene-Structured Nanowires of Silicon, Physical Review B, Vol. 60, Number 16, October 15, 1999, 593-600, The American Physical Society.	
		PENG, et al., Formation of Nanostructured Polymer Filaments in Nanochannels, JACS Communications, American Chemical Society, received February 6, 2003.	
		EDITED BY - H. BALTES, W. GÖPEL, J. HESSE, Sensors Update, Volume 4, Wiley-Vch Verlag GmbH, D-69469 Weinheim, Federal Republic of Germany, 1998, 1-220.	
		E.I. GIVARGIZOV, Fundamental Aspects of VLS Growth, Journal of Crystal Growth, 31, 1975, 20-30, North-Holland Publishing Company.	
		BJERNELD, et al., Laser-Induced Growth and Deposition of Noble-Metal Nanoparticles for Surface-Enhanced Raman Scattering, Nano Letters, 2003 Vol. 3., No. 5, 593-596, American Chemical Society.	

Examiner Signature	Date Considered
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		H. G. CRAIGHEAD, Issues In Nanotechnology Review - Nanoelectromechanical Systems, Science Mag. November 24, 2000, Vol. 290, 532-1535.	
		FRITZ, et al., Translating Biomolecular Recognition into Nanomechanics, Science Magazine, April 14, 2000, Vol. 288, 316-318.	
		WAGNER, et al., Vapor-Liquid-Solid Mechanism Of Single Crystal Growth, Applied Physics Letters, Vol. 4, Number 5, March 1, 1964, 89-90.	
		MICHAEL ROUKES, Nanoelectromechanical System Face The Future, Physicsweb, Feature: February 2001, 1-6, http://physicsweb.org/articles/world/14/2/8/2 .	
		CHENG, et al., Role of Electric Field on Formation of Silicon Nanowires, Journal of Applied Physics, Vol. 94, Number 2, July 15, 2003, 1190-1194 American Institute of Physics.	

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